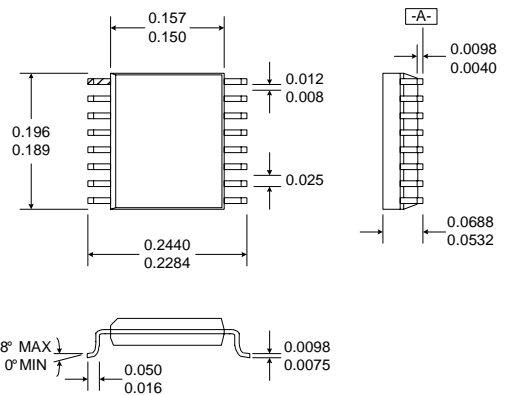


Typical Applications

- 3V CDMA/FM Cellular Systems
- Supports Dual-Mode AMPS/CDMA
- Supports Dual-Mode TACS/CDMA
- General Purpose Linear IF Amplifier
- Portable Battery-Powered Equipment
- Commercial and Consumer Systems

Product Description

The RF2619 is a complete AGC amplifier designed for the transmit section of 3V dual-mode CDMA/FM cellular applications. It is designed to amplify IF signals while providing more than 84dB of gain control range. Noise Figure, IP3, and other specifications are designed to be compatible with the IS-95 Interim Standard for CDMA cellular communications. This circuit is designed as part of the RFMD CDMA Chip Set, consisting of this Transmit IF AGC Amp, a Transmit Upconverter, a Receive LNA/Mixer, and a Receive IF AGC Amp. The IC is manufactured on an advanced high frequency Silicon Bipolar process and is packaged in a standard miniature 16-lead plastic SSOP package.

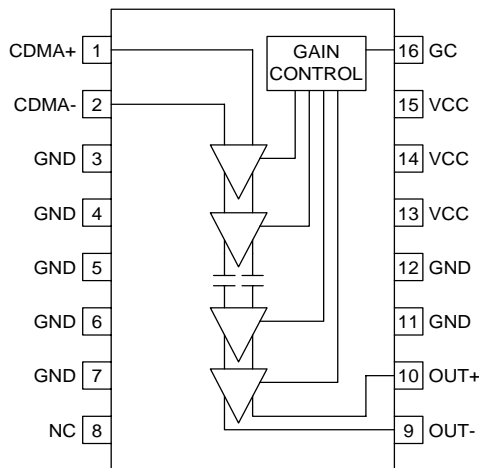


- NOTES:**
1. Shaded lead is Pin 1.
 2. All dimensions are excluding mold flash.
 3. Lead coplanarity - 0.005 with respect to datum "A".

Optimum Technology Matching® Applied

- Si BJT GaAs HBT GaAs MESFET
 Si Bi-CMOS SiGe HBT Si CMOS

Package Style: SSOP-16



Functional Block Diagram

Features

- Supports Dual Mode Operation
- -48dB to +42dB Gain Control Range
- Single 3V Power Supply
- Monolithic Construction
- 12MHz to 175MHz Operation
- Miniature Surface Mount Package

Ordering Information

RF2619 3V CDMA/FM Transmit AGC Amplifier
 RF2619 PCBA Fully Assembled Evaluation Board

RF Micro Devices, Inc.
 7628 Thorndike Road
 Greensboro, NC 27409, USA

Tel (336) 664 1233
 Fax (336) 664 0454
<http://www.rfmd.com>

RF2619

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	-0.5 to +7.0	V _{DC}
Control Voltage	-0.5 to +5.0	V
Input Power Levels	+10	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



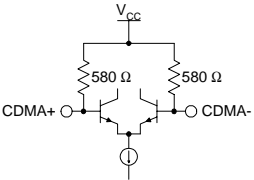
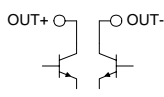
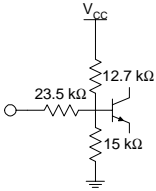
Caution! ESD sensitive device.

RF Micro Devices believes the furnished information is correct and accurate at the time of this printing. However, RF Micro Devices reserves the right to make changes to its products without notice. RF Micro Devices does not assume responsibility for the use of the described product(s).

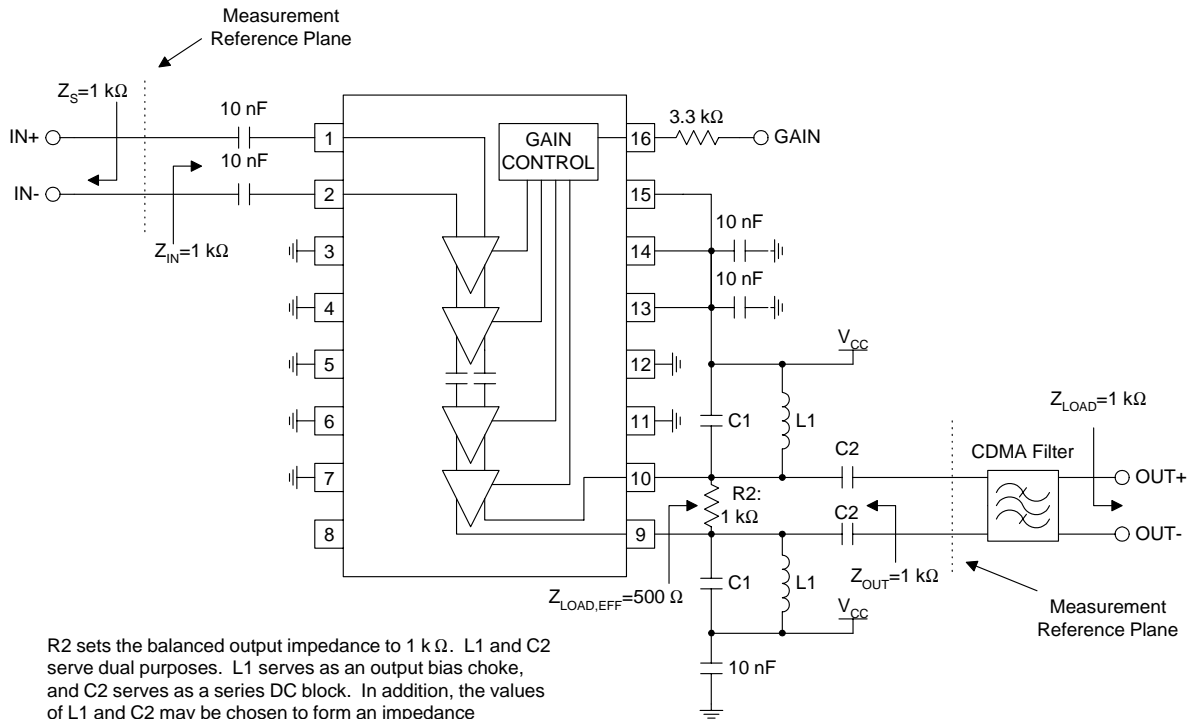
Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall					T=25°C, 130MHz, V _{CC} =3.0V, Pin=-40dBm, Z _S =1kΩ, Z _L =1kΩ, 1kΩ External Output Terminating Resistor (Effective Z _L =500Ω) (See Application Example)
Frequency Range		12 to 175		MHz	
Maximum Gain	+39	+42		dB	V _{GC} =2.4V
Minimum Gain		-48	-45	dB	V _{GC} =0.3V
Gain Slope		57		dB/V	Measured in 0.5V increments
Gain Control Voltage Range		0 to 3		V _{DC}	
Gain Control Input Impedance		30		kΩ	
Noise Figure		10.5	13	dB	At maximum gain and 130MHz
Input IP3	-26	-25		dBm	At +10 gain and referenced to 1kΩ, Pin=-45dBm per tone
Input Impedance		1		kΩ	Differential
Stability (Max VSWR)	10:1				Spurious < -70dBm
Power Supply					
Voltage		2.7 to 3.3		V	
Current Consumption		23	25	mA	Maximum gain, V _{CC} =3.0V
Current Consumption		22	24	mA	Minimum gain, V _{CC} =3.0V

10

IF AMPLIFIERS

Pin	Function	Description	Interface Schematic
1	CDMA+	CDMA balanced input pin. This pin is internally DC-biased and should be DC-blocked if connected to a device with a DC level, other than V_{CC} , present. A DC to connection to V_{CC} is acceptable. For single-ended input operation, one pin is used as an input and the other CDMA input is AC-coupled to ground. The balanced input impedance is $1\text{ k}\Omega$, while the single-ended input impedance is 500Ω .	
2	CDMA-	Same as pin 2, except complementary input.	See pin 1 schematic.
3	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
4	GND	Same as pin 3.	
5	GND	Same as pin 3.	
6	GND	Same as pin 3.	
7	GND	Same as pin 3.	
8	NC	No Connection pin. This pin is internally biased and should not be connected to any external circuitry, including ground or V_{CC} .	
9	OUT-	Balanced output pin. This is an open-collector output, designed to operate into a 500Ω balanced load. The load sets the operating impedance, but an external choke or matching inductor to V_{CC} must also be supplied in order to correctly bias this output. This bias inductor is typically incorporated in the matching network between the output and next stage. Because this pin is biased to V_{CC} , a DC-blocking capacitor must be used if the next stage's input has a DC path to ground.	
10	OUT+	Same as pin 9, except complementary output.	See pin 9 schematic.
11	GND	Same as pin 3.	
12	GND	Same as pin 3.	
13	VCC	Supply Voltage pin. External bypassing is required. The trace length between the pin and the bypass capacitors should be minimized. The ground side of the bypass capacitors should connect immediately to ground plane. Pins 13, 14, and 15 may share one bypass capacitor if trace lengths are kept minimal.	
14	VCC	Same as pin 13.	
15	VCC	Same as pin 13.	
16	GC	Analog gain adjustment for all amplifiers. Valid control ranges are from 0V to 3.0V . Maximum gain is selected with 3.0V . Minimum gain is selected with 0V . These voltages are valid only for a $3.3\text{ k}\Omega$ DC source impedance.	

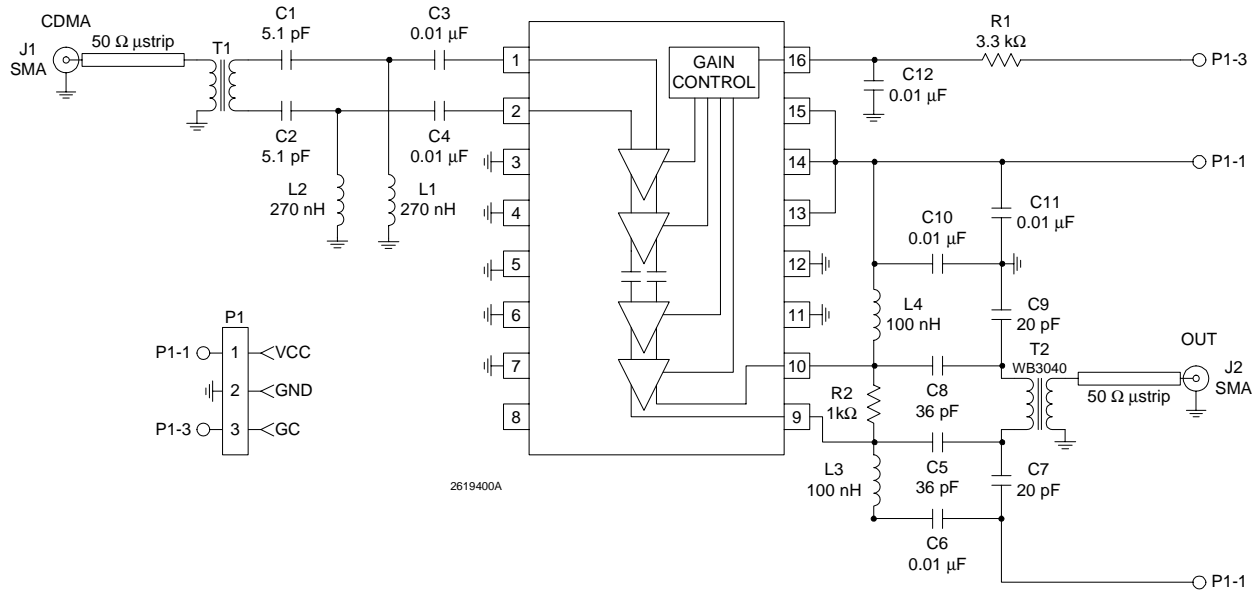
Application Schematic



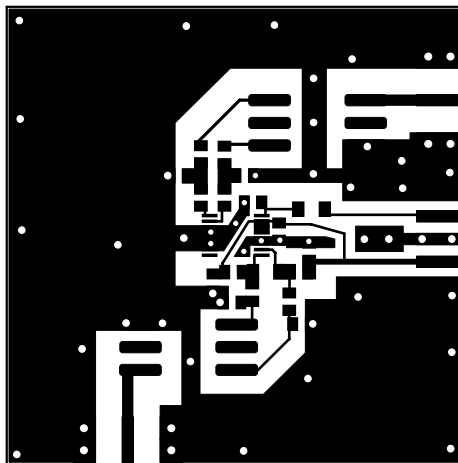
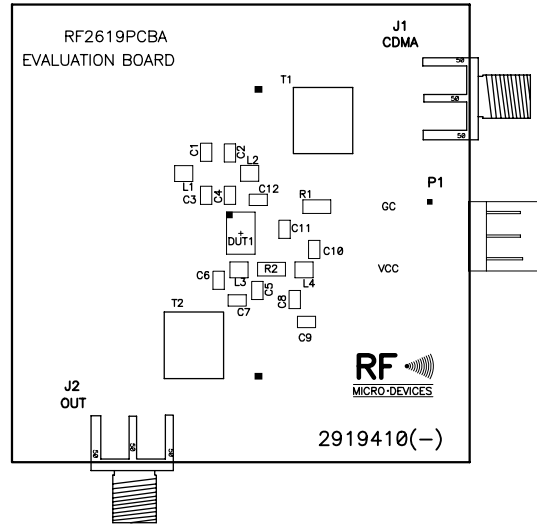
R2 sets the balanced output impedance to 1 k Ω . L1 and C2 serve dual purposes. L1 serves as an output bias choke, and C2 serves as a series DC block. In addition, the values of L1 and C2 may be chosen to form an impedance matching network if the load impedance is not 1 k Ω . Otherwise, the values of L1 and C1 are chosen to form a parallel-resonant tank circuit at the IF when the IF filter's input impedance is 1 k Ω .

Evaluation Board Schematic

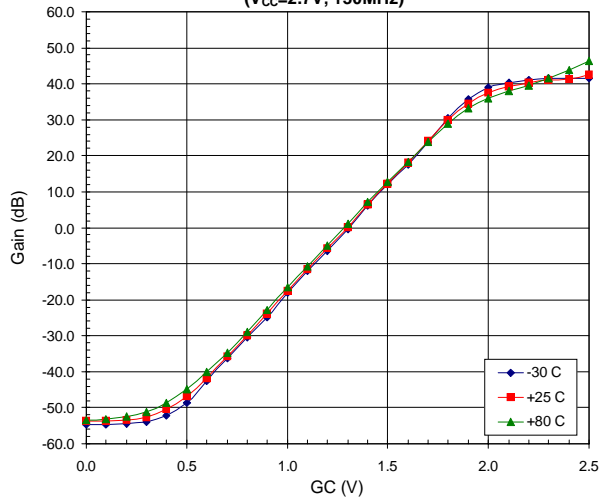
(Download [Bill of Materials](http://www.rfmd.com) from www.rfmd.com.)



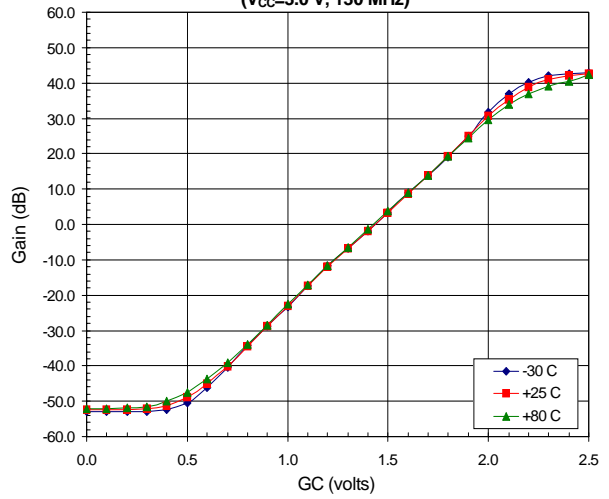
Evaluation Board Layout



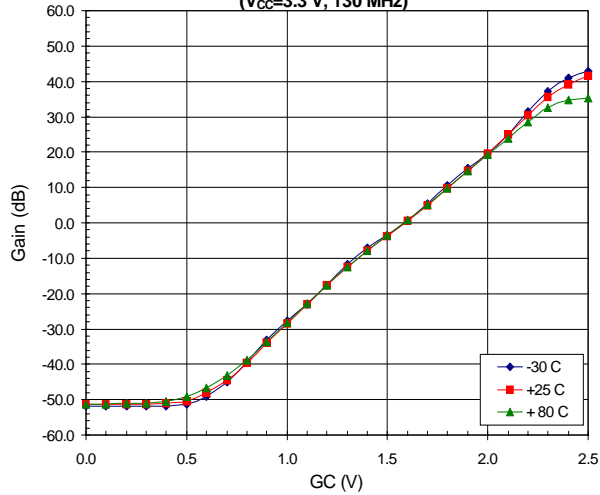
Gain versus Gain Control Voltage
($V_{CC}=2.7V$, 130MHz)



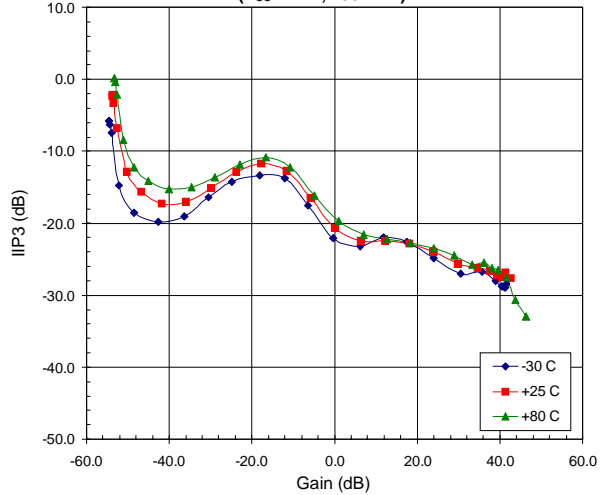
RF2619 Gain versus Gain Control Voltage
($V_{CC}=3.0V$, 130 MHz)



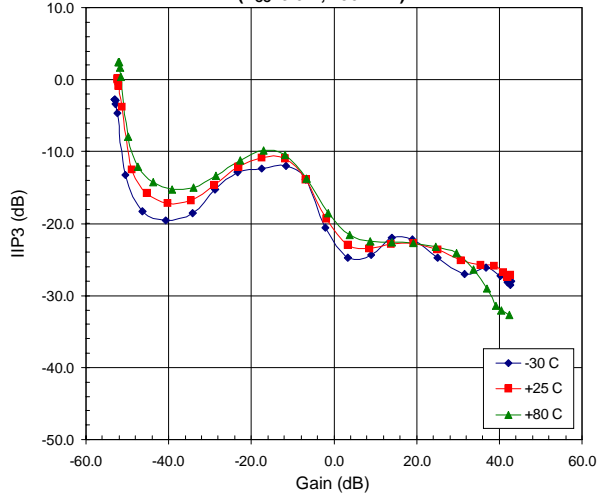
Gain versus Gain Control Voltage
($V_{CC}=3.3V$, 130 MHz)



IIP3 versus Gain
($V_{CC}=2.7V$, 130 MHz)



IIP3 versus Gain
($V_{CC}=3.0V$, 130 MHz)



IIP3 versus Gain
($V_{CC}=3.3V$, 130 MHz)

